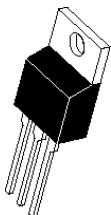
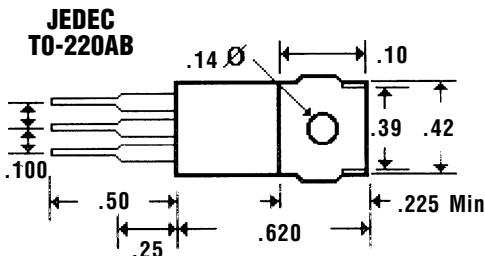


Description



Mechanical Dimensions



Features

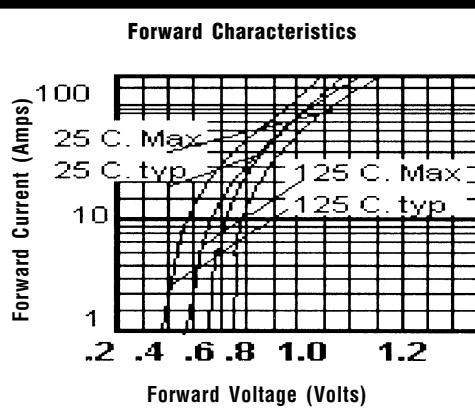
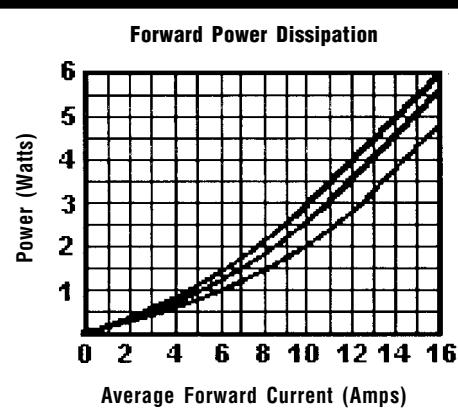
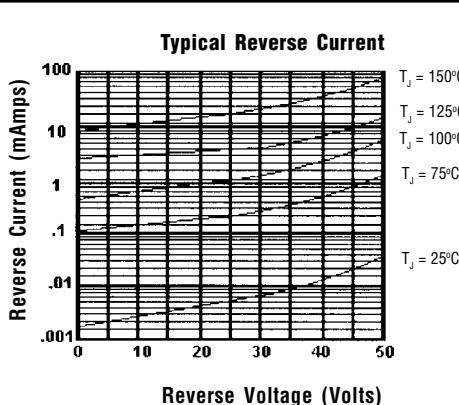
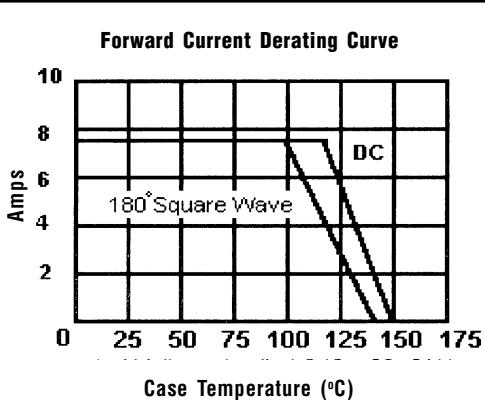
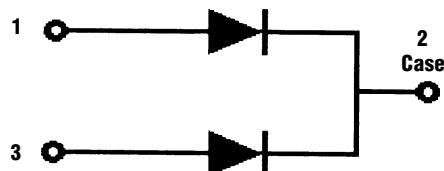
- HIGH CURRENT CAPABILITY W/LOW V_F
- HIGH EFFICIENCY w/LOW POWER LOSS
- HIGH SURGE VOLTAGE AND TRANSIENT PROTECTION
- CENTER TAP CONFIGURATION
- 150°C OPERATING JUNCTION TEMPERATURE
- MEETS UL SPECIFICATION 94V-0

Electrical Characteristics @ 25°C.

FBR1535 & 1545

Units

Maximum Ratings	FBR1535	FBR1545	Units
Peak Repetitive Reverse Voltage... V_{RRM}	3.5	4.5	Volts
Working Peak Reverse Voltage... V_{RWM}	3.5	4.5	Volts
DC Blocking Voltage... V_{DC}	3.5	4.5	Volts
Average Forward Rectified Current... $I_{F(AV)}$ @ $T_c = 105^\circ C$	Per Diode Per Device	7.5 15	Amps Amps
Repetitive Peak Forward Surge Current... I_{FM} $T_c = 105^\circ C$ (Rated V_R , Square Wave, 20KHZ)	Per Diode	15	Amps
Non-Repetitive Peak Forward Surge Current... I_{FSM} @ Rated Load Conditions, 1/2 Wave, Single Phase, 60HZ	150	Amps
Repetitive Peak Reverse Surge Current... I_{RSM} 2uS, 1.0 KHZ	1.0	Amps
Forward Voltage... V_F @ $I_F = 7.5$ Amps, $T_c = 125^\circ C$ @ $I_F = 15$ Amps, $T_c = 125^\circ C$ @ $I_F = 15$ Amps, $T_c = 25^\circ C$577284	Volts Volts Volts
DC Reverse Current... I_R @ Rated DC Blocking Voltage	$T_c = 25^\circ C$ $T_c = 125^\circ C$	0.1 15	mAmps mAmps
Thermal Resistance, Junction to Case... R_{\thetaJC}	3.0	°C / W
Thermal Resistance, Junction to Ambient... R_{\thetaJA}	60	°C / W
Operating Temperature Range... T_J	-65 to 150	°C
Storage Temperature Range... T_{STRG}	-65 to 175	°C

Common Cathode,
Suffix "C"


Ratings at
25 Deg. C ambient
temperature
unless otherwise
specified.

Single Phase Half
Wave, 60 Hz
Resistive or
Inductive Load.

For Capacitive
Load, Derate
Current by 20%.

- NOTES:**
1. Measured @ 1 MHZ and applied reverse voltage of 4.0V.
 2. Thermal Resistance Junction to Case, Jedec Method.
 3. When Mounted to heat sink, from body.